MOSFETs Silicon N-Channel MOS

SSM6N7002CFU

1. Applications

- High-Speed Switching

2. Features

(1) Gate-Source diode for protection

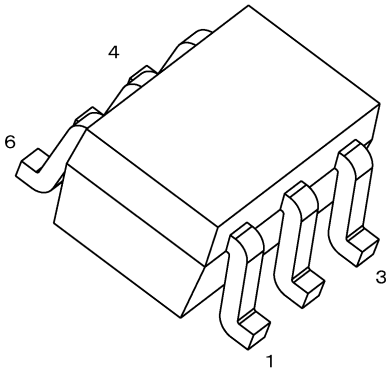
(2) Low drain-source on-resistance

: $R_{DS(ON)}$ = 2.8 Ω (typ.) (@V_{GS} = 10 V, I_D = 100 mA)

$R_{DS(ON)}$ = 3.1 Ω (typ.) (@V_{GS} = 5 V, I_D = 100 mA)

$R_{DS(ON)}$ = 3.2 Ω (typ.) (@V_{GS} = 4.5 V, I_D = 100 mA)

3. Packaging and Pin Assignment



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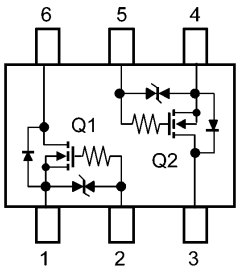


1. Source1
2. Gate1
3. Drain2
4. Source2
5. Gate2
6. Drain1

Start of commercial production
2015-04

2015-04-13
Rev.1.0

4. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C) (Q1,Q2 Common)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	60	V
Gate-source voltage		V_{GSS}	±20	
Drain current (DC)	(Note 1)	I_D	170	mA
Drain current (pulsed)	(Note 1), (Note 2)	I_{DP}	680	
Power dissipation	(Note 3)	P_D	285	mW
Channel temperature		T_{ch}	150	°C
Storage temperature		T_{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Pulse width (PW) ≤ 10 μs, duty ≤ 1%

Note 3: Device mounted on an FR-4 board.(total dissipation)
(25.4 mm × 25.4 mm × 1.6 mm ,Cu pad: 645 mm^2)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, $R_{th(ch-a)}$, and the drain power dissipation, P_D, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

5. Electrical Characteristics

5.1. Static Characteristics (Unless otherwise specified, T_a = 25 °C)(Q1,Q2 Common)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	V_{DS} = 0 V, V_{GS} = ±16 V	—	—	±2	μA
			V_{DS} = 0 V, V_{GS} = ±10 V	—	—	±0.5	
			V_{DS} = 0 V, V_{GS} = ±5 V	—	—	±0.1	
Drain cut-off current		I_{DSS}	V_{DS} = 60 V, V_{GS} = 0 V	—	—	1	μA
			V_{DS} = 60 V, V_{GS} = 0 V, T_j = 150 °C	—	—	200	
Drain-source breakdown voltage		$V_{(BR)DSS}$	I_D = 250 μA, V_{GS} = 0 V	60	—	—	V
Gate threshold voltage	(Note 1)	V_{th}	I_D = 250 μA, V_{DS} = V_{GS}	1.1	—	2.1	V
Drain-source on-resistance	(Note 2)	$R_{DS(ON)}$	I_D = 100 mA, V_{GS} = 10 V	—	2.8	3.9	Ω
			I_D = 100 mA, V_{GS} = 10 V, T_j = 150 °C	—	5.4	8.1	
			I_D = 100 mA, V_{GS} = 5 V	—	3.1	4.4	
			I_D = 100 mA, V_{GS} = 4.5 V	—	3.2	4.7	
Forward transfer admittance	(Note 2)	$\|Y_{fs}\|$	V_{DS} = 10 V, I_D = 200 mA	—	450	—	mS

Note 1: Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (250 μA for this device). Then, for normal switching operation, $V_{GS(ON)}$ must be higher than V_{th}, and $V_{GS(OFF)}$ must be lower than V_{th}. This relationship can be expressed as: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$.
Take this into consideration when using the device.

Note 2: Pulse measurement.

5.2. Dynamic Characteristics (Unless otherwise specified, T_a = 25 °C)(Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	—	11	17	pF
Reverse transfer capacitance	C_{rss}		—	0.7	—	
Output capacitance	C_{oss}		—	3	—	
Switching time (turn-on delay time)	$t_{d(on)}$	V_{DD} = 40 V, I_D = 160 mA, V_{GS} = 0 to 10 V, R_G = 50 Ω	—	2	4	ns
Switching time (rise time)	t_r		—	3	—	
Switching time (turn-off delay time)	$t_{d(off)}$		—	7	14	
Switching time (fall time)	t_f		—	24	—	

5.3. Switching Time Test Circuit

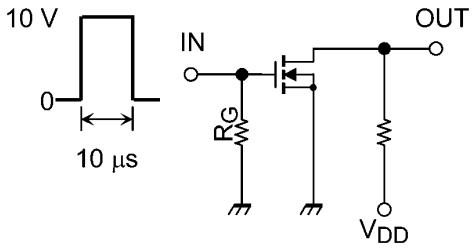


Fig. 5.3.1 Switching Time Test Circuit

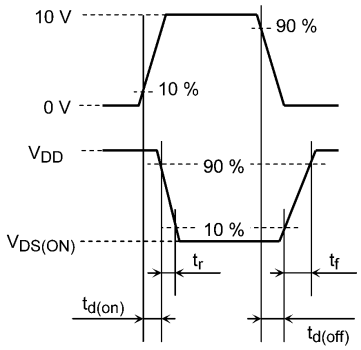


Fig. 5.3.2 Input Waveform/Output Waveform

5.4. Gate Charge Characteristics (Unless otherwise specified, T_a = 25 °C) (Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	V_{DS} = 30 V, I_D = 200 mA, V_{GS} = 4.5 V	—	0.27	0.35	nC
Gate-source charge	Q_{gs}		—	0.08	—	
Gate-drain charge	Q_{gd}		—	0.08	—	

5.5. Source-Drain Characteristics (Unless otherwise specified, T_a = 25 °C) (Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	V_{DSF}	I_D = -115 mA, V_{GS} = 0 V	—	-0.87	-1.2	V

Note 1: Pulse measurement.

6. Marking

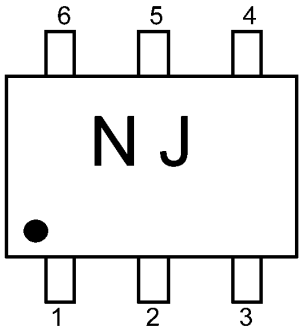


Fig. 6.1 Marking

7. Characteristics Curves (Q1,Q2 Common) (Note)

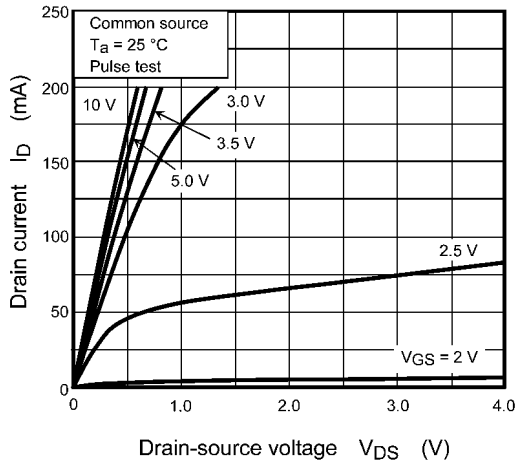


Fig. 7.1 I_D - V_{DS}

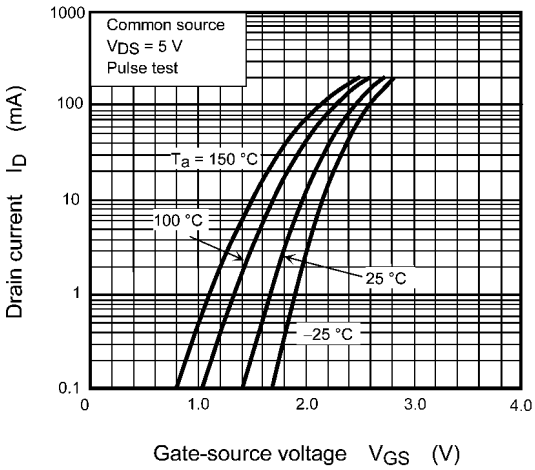


Fig. 7.2 I_D - V_{GS}

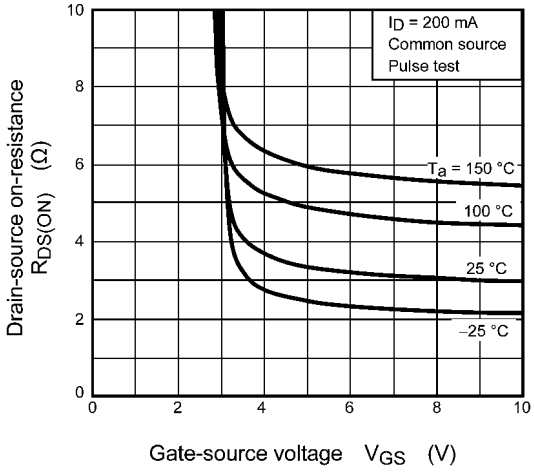


Fig. 7.3 $R_{DS(ON)}$ - V_{GS}

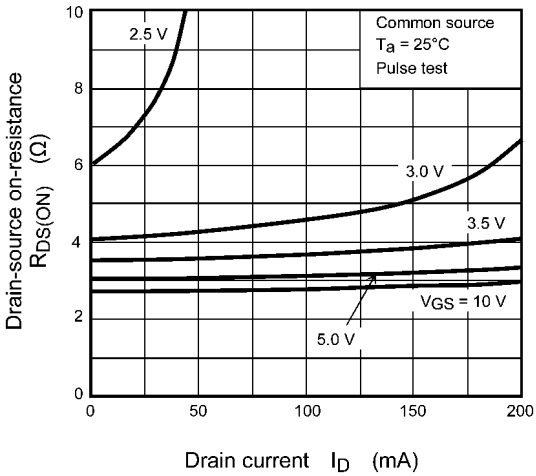


Fig. 7.4 $R_{DS(ON)}$ - I_D

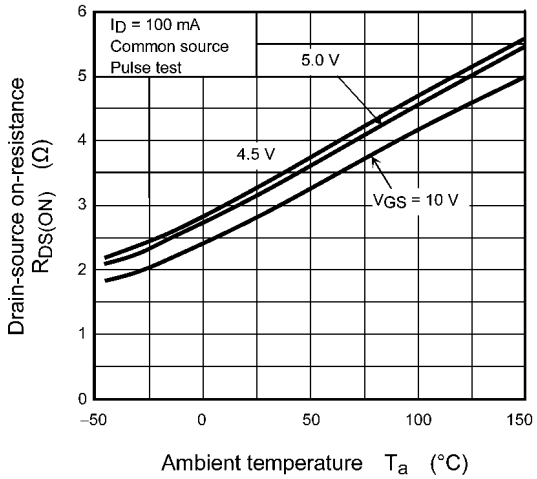


Fig. 7.5 $R_{DS(ON)}$ - T_a

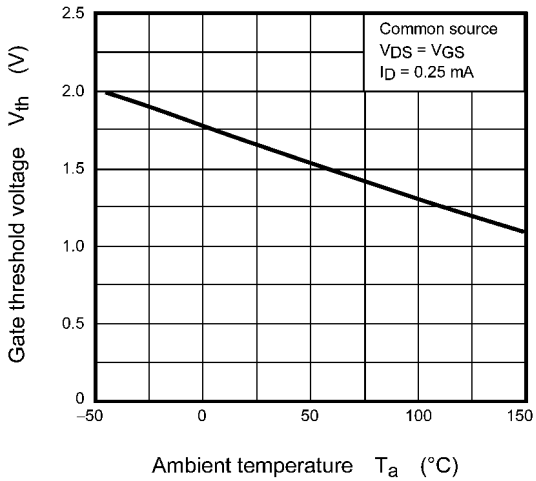


Fig. 7.6 V_{th} - T_a

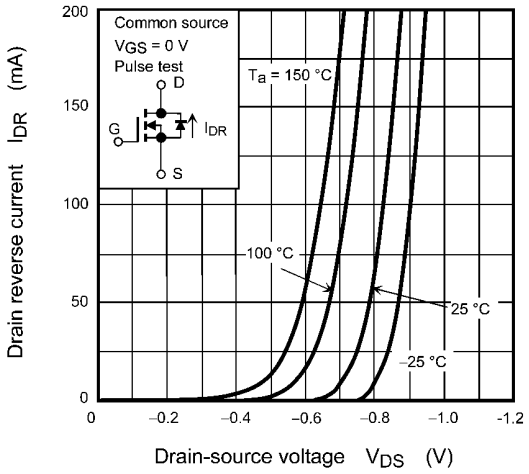


Fig. 7.7 I_{DR} - V_{DS}

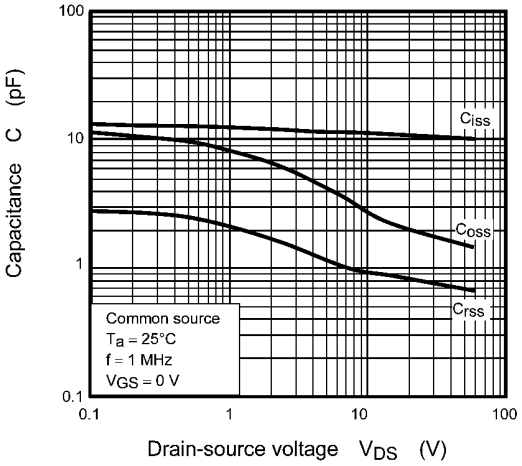


Fig. 7.8 C - V_{DS}

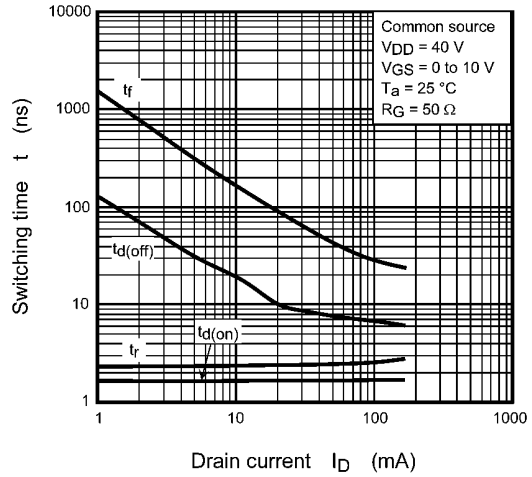


Fig. 7.9 t - I_D

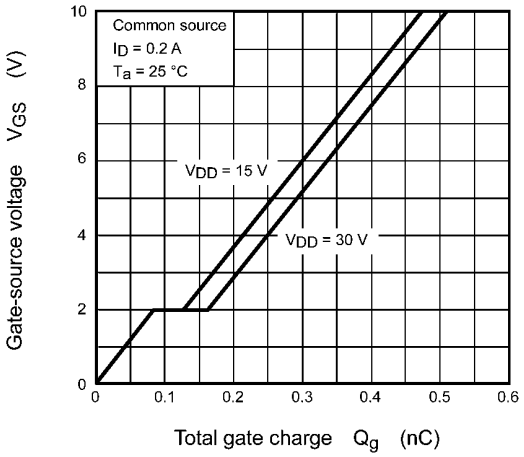


Fig. 7.10 Dynamic Input Characteristics

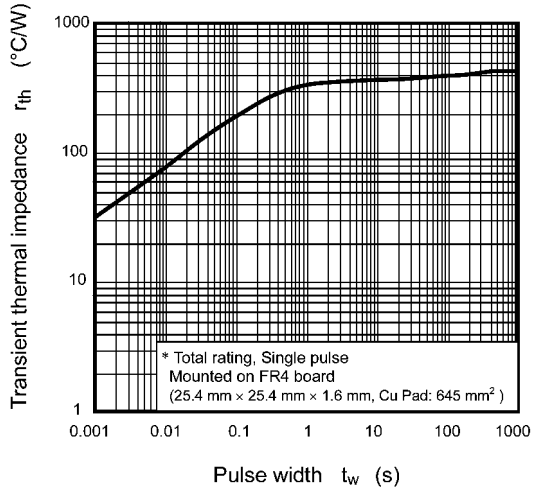


Fig. 7.11 r_{th} - t_w

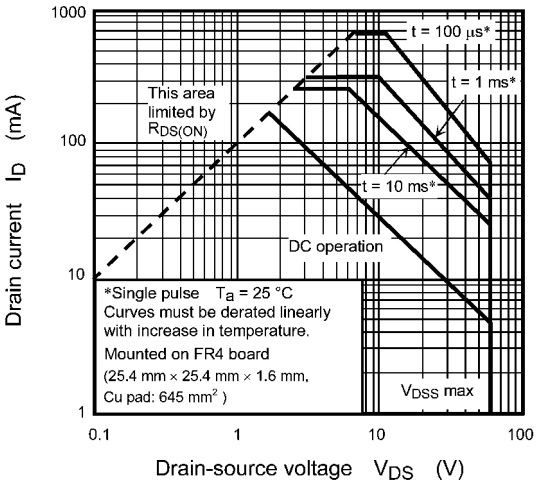
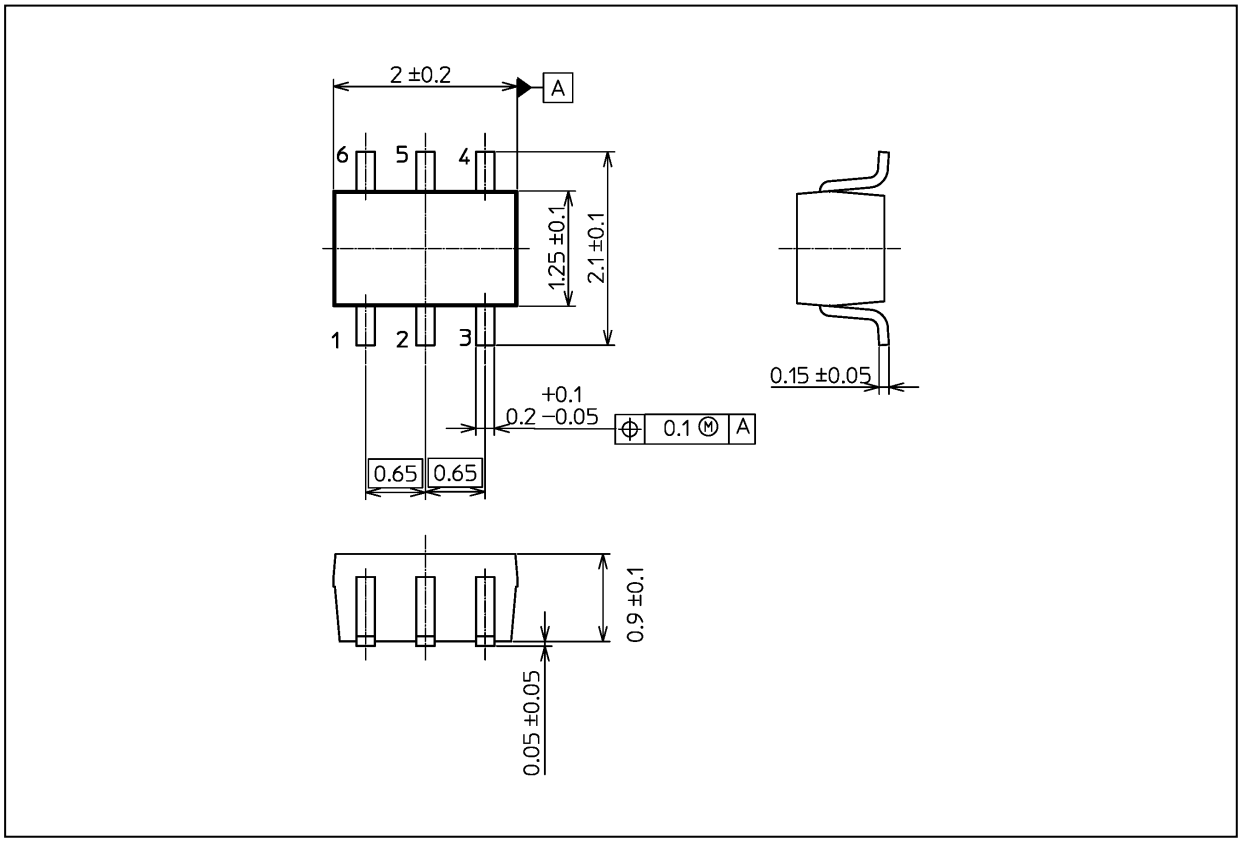


Fig. 7.12 Safe Operating Area

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 6.8 mg (typ.)

Package Name(s)
Nickname: US6

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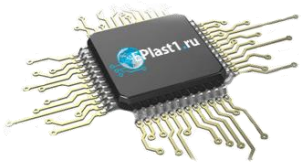

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